

# ESD131-B1-W0201

## Protection Devices

TVS (Transient Voltage Suppressor)

Bi-directional, 5.5 V, 0.23 pF, 0201, RoHS and Halogen Free compliant

## Features

- ESD / transient protection according to:
  - IEC61000-4-2 (ESD):  $\pm 20$  kV (air / contact discharge)
  - IEC61000-4-4 (EFT):  $\pm 2.5$  kV /  $\pm 60$  A (5/50 ns)
  - IEC61000-4-5 (Surge):  $\pm 3.5$  A (8/20  $\mu$ s)
- Bi-directional working voltage up to:  $V_{RWM} = \pm 5.5$  V
- Line capacitance:  $C_L = 0.23$  pF (typical) at  $f = 1$  MHz
- Clamping voltage:  $V_{CL} = 13$  V (typical) at  $I_{TLP} = 16$  A with  $R_{DYN} = 0.66 \Omega$  (typical)
- Very low reverse current:  $I_R < 100$  nA (max.)
- Small form factor SMD size 0201 and low profile (0.58 mm x 0.28 mm x 0.15 mm)
- Bidirectional and symmetric I/V characteristics for optimized design and assembly
- Pb-free (RoHS compliant) and halogen free package



Guidelines for optimized PCB design and assembly process are available in [\[2\]](#).

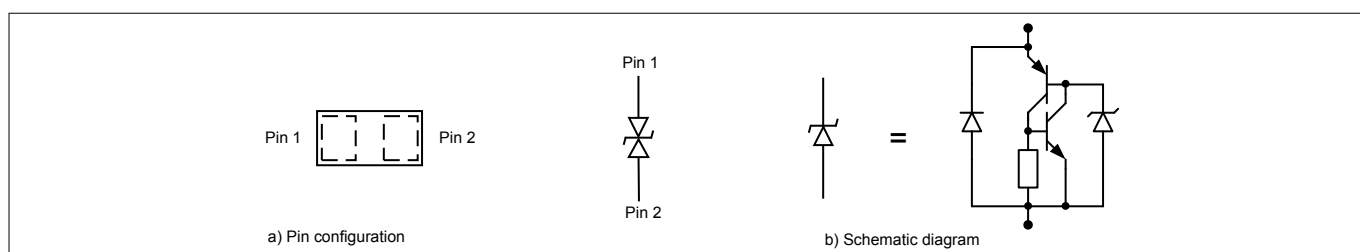
## Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22

## Application examples

- USB 3.0, Firewire, DVI, HDMI, S-ATA, DisplayPort, Thunderbolt
- Mobile HDMI Link, MDDI, MIPI, SWP / NFC

## Device information



**Figure 1** Pin configuration and schematic diagram

**Table 1** Part information

| Type            | Package | Configuration          | Marking code    |
|-----------------|---------|------------------------|-----------------|
| ESD131-B1-W0201 | WLL-2-3 | 1 line, bi-directional | T <sup>1)</sup> |

<sup>1</sup> The device does not have any marking on the device top. The marking code is between the pads.

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**Maximum ratings**

## **1 Maximum ratings**

Note:  $T_A = 25\text{ °C}$ , unless otherwise specified <sup>1)</sup>

**Table 2 Maximum ratings**

| Parameter                        | Symbol              | Values     | Unit |
|----------------------------------|---------------------|------------|------|
| Reverse working voltage          | $V_{RWM}$           | $\pm 5.5$  | V    |
| ESD discharge <sup>2)</sup>      | $V_{ESD}$ (contact) | $\pm 20$   | kV   |
|                                  | $V_{ESD}$ (air)     | $\pm 20$   |      |
| Peak pulse power <sup>3)</sup>   | $P_{PK}$            | 26         | W    |
| Peak pulse current <sup>3)</sup> | $I_{PP}$            | $\pm 3.5$  | A    |
| Operating temperature range      | $T_{OP}$            | -55 to 125 | °C   |
| Storage temperature              | $T_{stg}$           | -65 to 150 | °C   |

**Attention:** *Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.*

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<sup>1</sup> Device is electrically symmetrical

<sup>2</sup>  $V_{ESD}$  according to IEC61000-4-2 (R = 330  $\Omega$ , C = 150 pF discharge network)

<sup>3</sup> Stress pulse: 8/20 $\mu$ s current waveform according to IEC61000-4-5

Electrical characteristics

## 2 Electrical characteristics

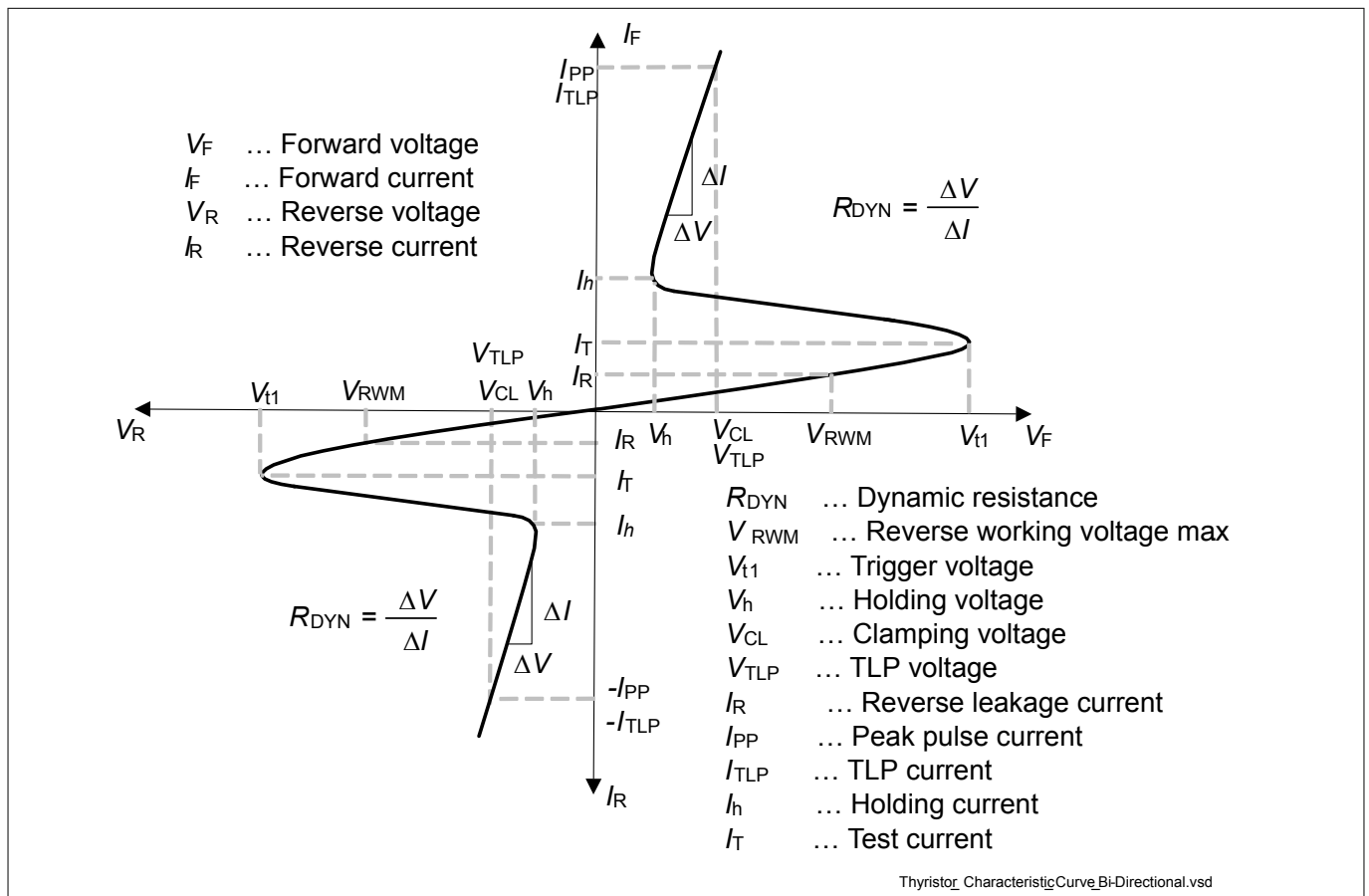


Figure 2 Definitions of electrical characteristics

## Electrical characteristics

**Table 3 DC characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified) <sup>1)</sup>**

| Parameter               | Symbol   | Values |      |      | Unit | Note or test condition |
|-------------------------|----------|--------|------|------|------|------------------------|
|                         |          | Min.   | Typ. | Max. |      |                        |
| Breakdown voltage       | $V_{br}$ | 6      | 8    | 10.5 | V    | $I_R = 1\text{ mA}$    |
| Holding voltage         | $V_h$    | –      | 1.9  | –    | V    | $I_R = I_h$            |
| Holding reverse current | $I_h$    | –      | 25   | –    | mA   | $V_R = V_h$            |
| Reverse current         | $I_R$    | –      | –    | 100  | nA   | $V_R = 5.5\text{ V}$   |

**Table 4 AC characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified)**

| Parameter        | Symbol | Values |      |      | Unit | Note or test condition                    |
|------------------|--------|--------|------|------|------|-------------------------------------------|
|                  |        | Min.   | Typ. | Max. |      |                                           |
| Line capacitance | $C_L$  | –      | 0.23 | 0.35 | pF   | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$   |
|                  |        | –      | 0.20 | –    |      | $V_R = 0\text{ V}$ , $f = 2.5\text{ GHz}$ |

**Table 5 ESD and Surge characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified) <sup>1)</sup>**

| Parameter                        | Symbol           | Values |      |      | Unit | Note or test condition                           |
|----------------------------------|------------------|--------|------|------|------|--------------------------------------------------|
|                                  |                  | Min.   | Typ. | Max. |      |                                                  |
| Clamping voltage <sup>2)</sup>   | V <sub>CL</sub>  | –      | 8.5  | –    | V    | I <sub>TLP</sub> = 8 A, t <sub>p</sub> = 100 ns  |
|                                  |                  | –      | 13   | –    |      | I <sub>TLP</sub> = 16 A, t <sub>p</sub> = 100 ns |
| Clamping voltage <sup>3)</sup>   |                  | –      | 3    | –    |      | I <sub>PP</sub> = 1 A, t <sub>p</sub> = 8/20 μs  |
|                                  |                  | –      | 5.5  | –    |      | I <sub>PP</sub> = 3 A, t <sub>p</sub> = 8/20 μs  |
| Dynamic resistance <sup>2)</sup> | R <sub>DYN</sub> | –      | 0.66 | –    | Ω    | t <sub>p</sub> = 100 ns                          |

<sup>1)</sup> Device is electrically symmetrical

<sup>2)</sup> Please refer to Application Note AN210 [\[1\]](#). TLP parameters:  $Z_0 = 50\text{ }\Omega$ ,  $t_p = 100\text{ ns}$ ,  $t_r = 0.6\text{ ns}$ .

<sup>3)</sup> Stress pulse: 8/20 $\mu\text{s}$  current waveform according to IEC61000-4-5

## Typical characteristic diagrams

### 3 Typical characteristic diagrams

Note:  $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

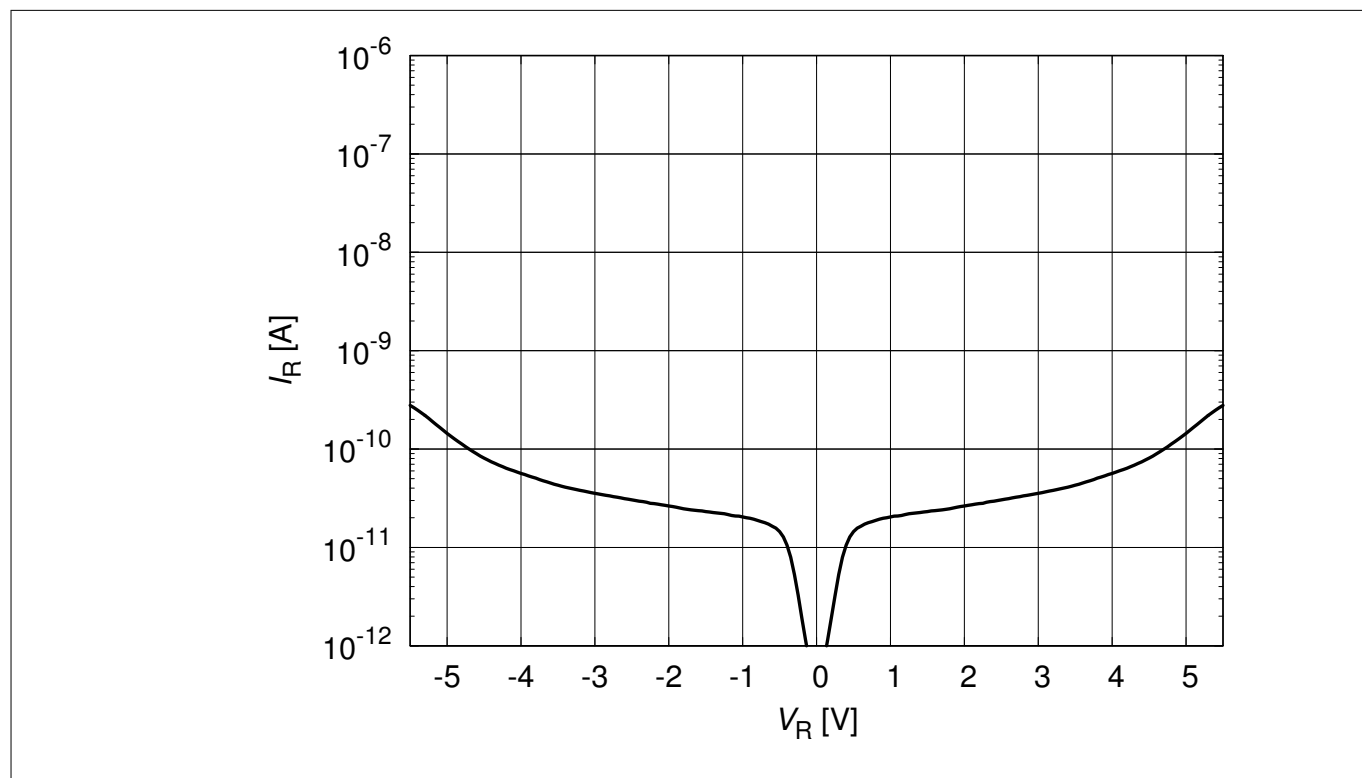


Figure 3 Reverse leakage current:  $I_R = f(V_R)$

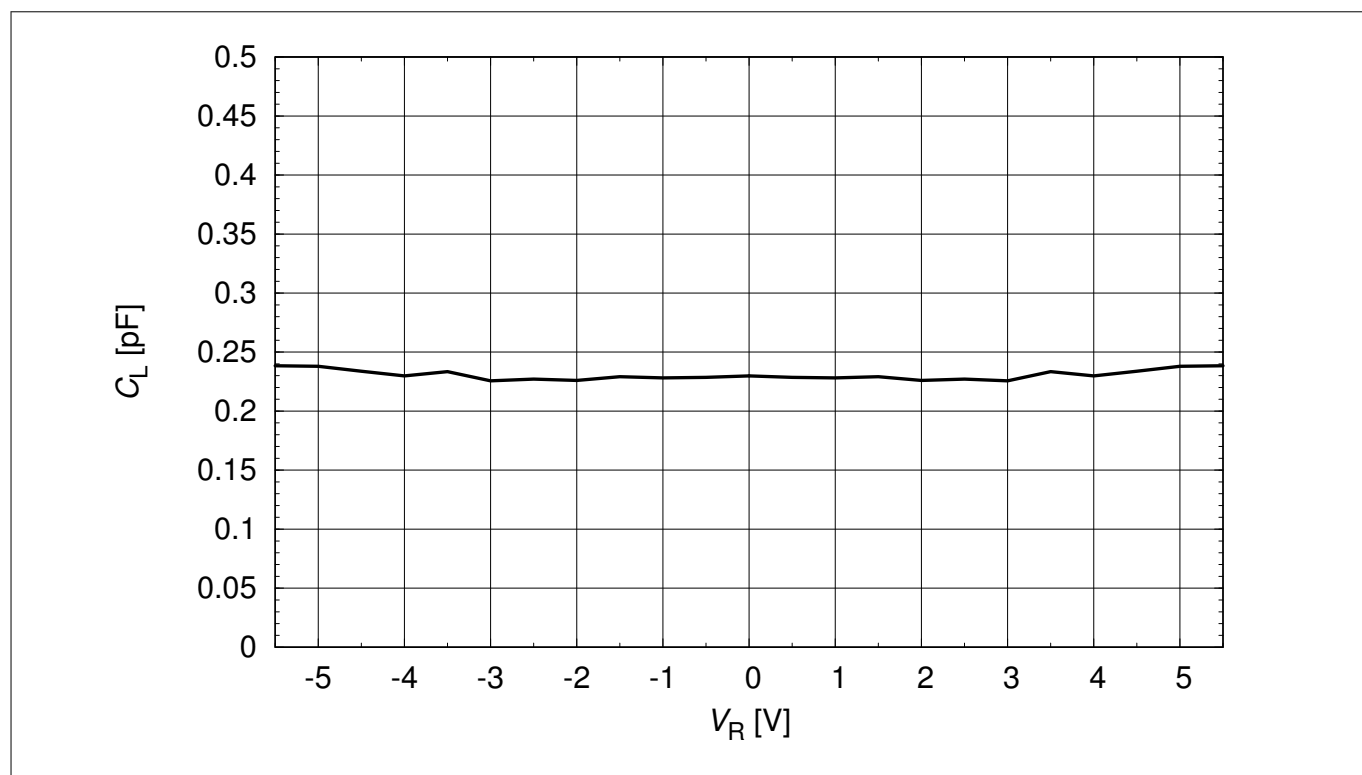
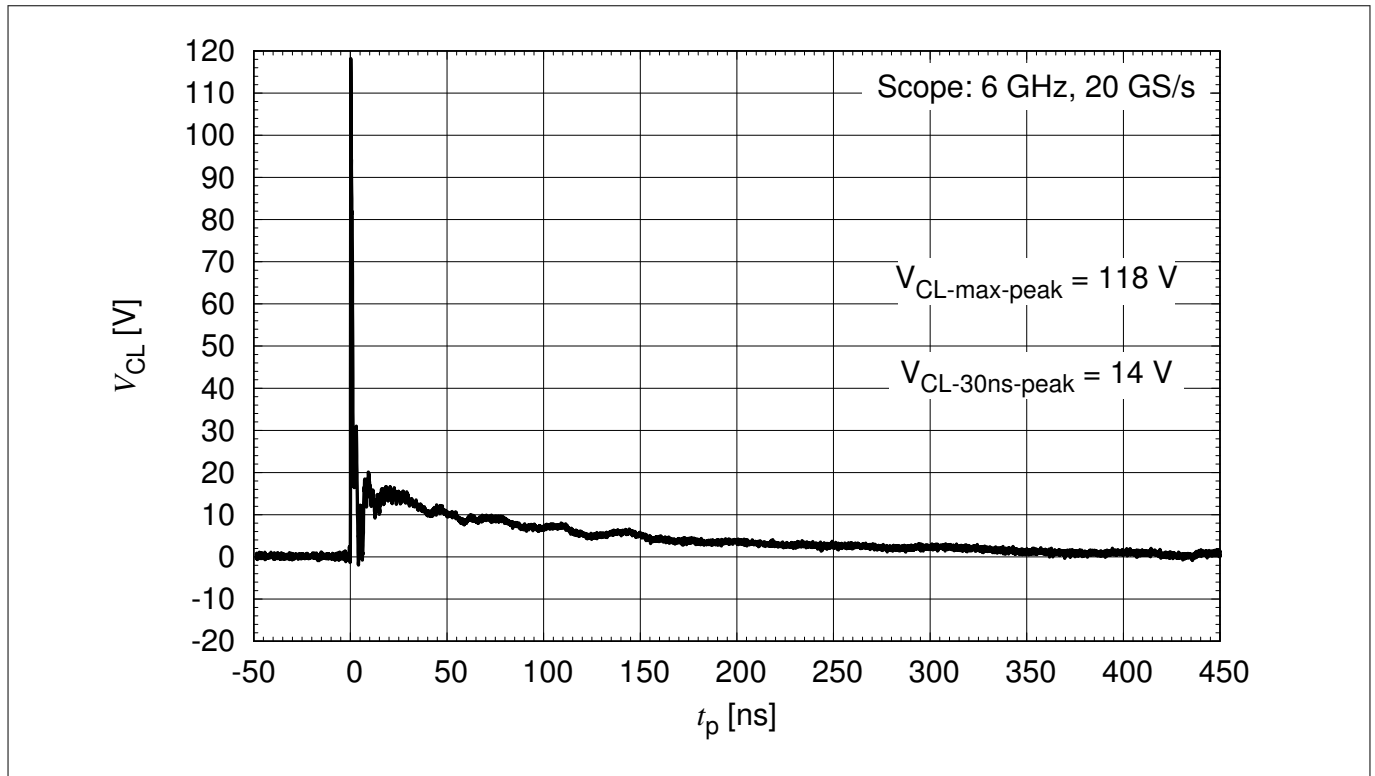
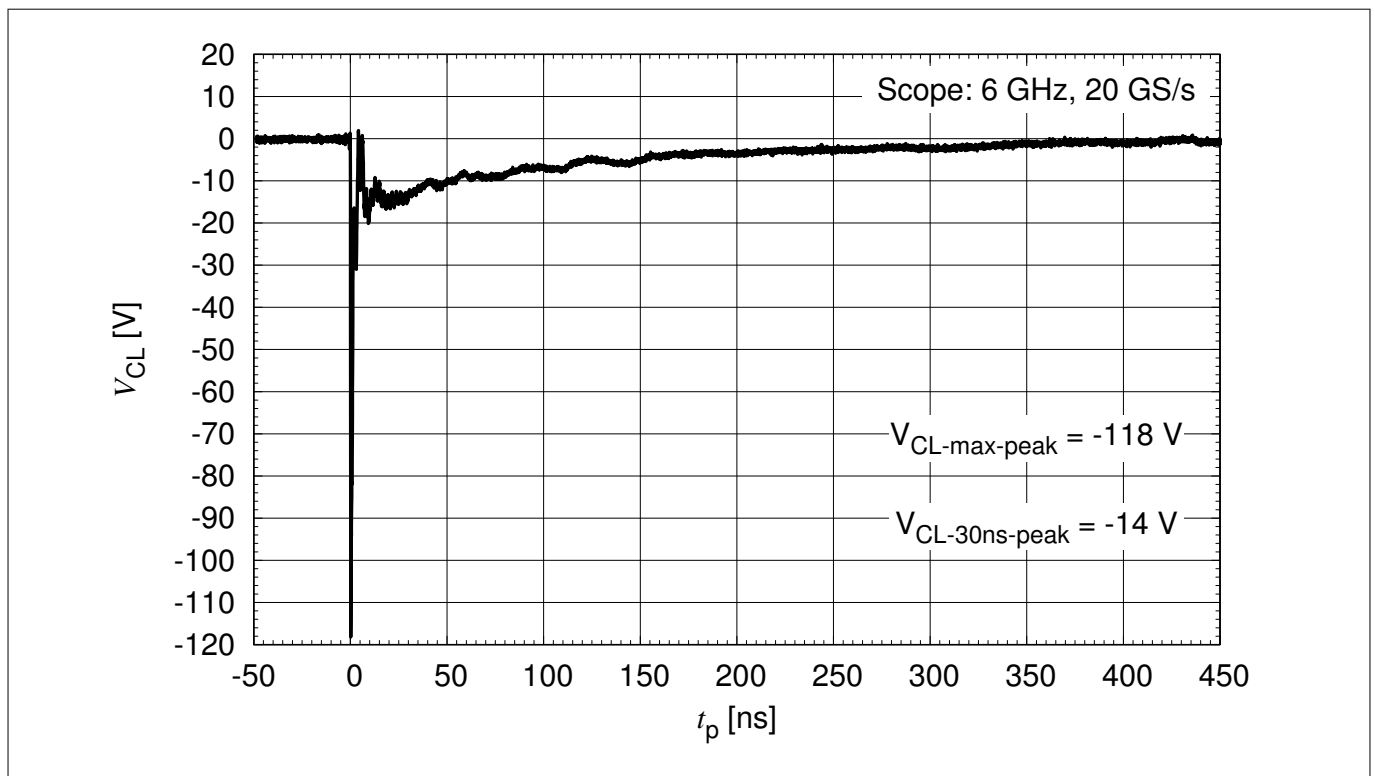


Figure 4 Line capacitance:  $C_L = f(V_R)$ ,  $f = 1\text{ MHz}$

Typical characteristic diagrams

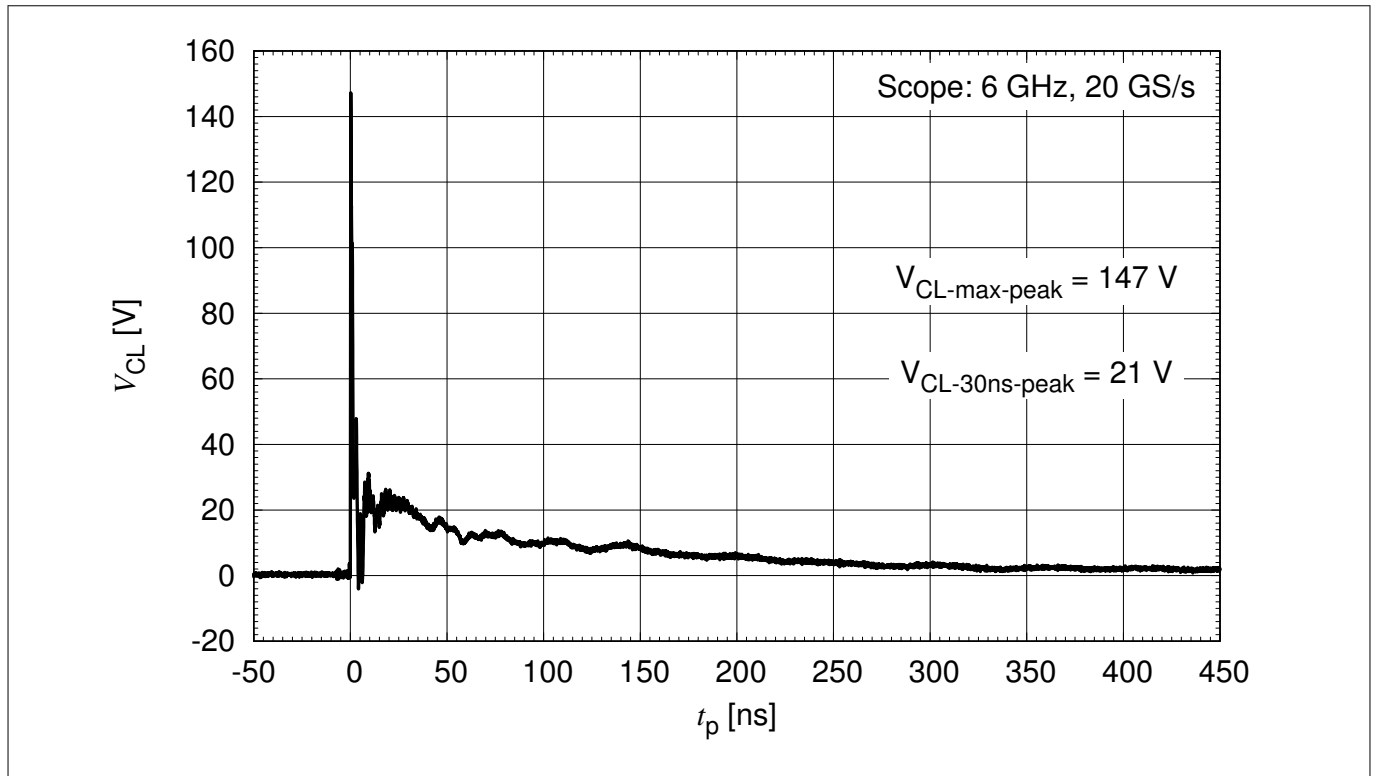


**Figure 5** Clamping voltage (ESD):  $V_{CL} = f(t)$ , 8 kV positive pulse according to IEC61000-4-2

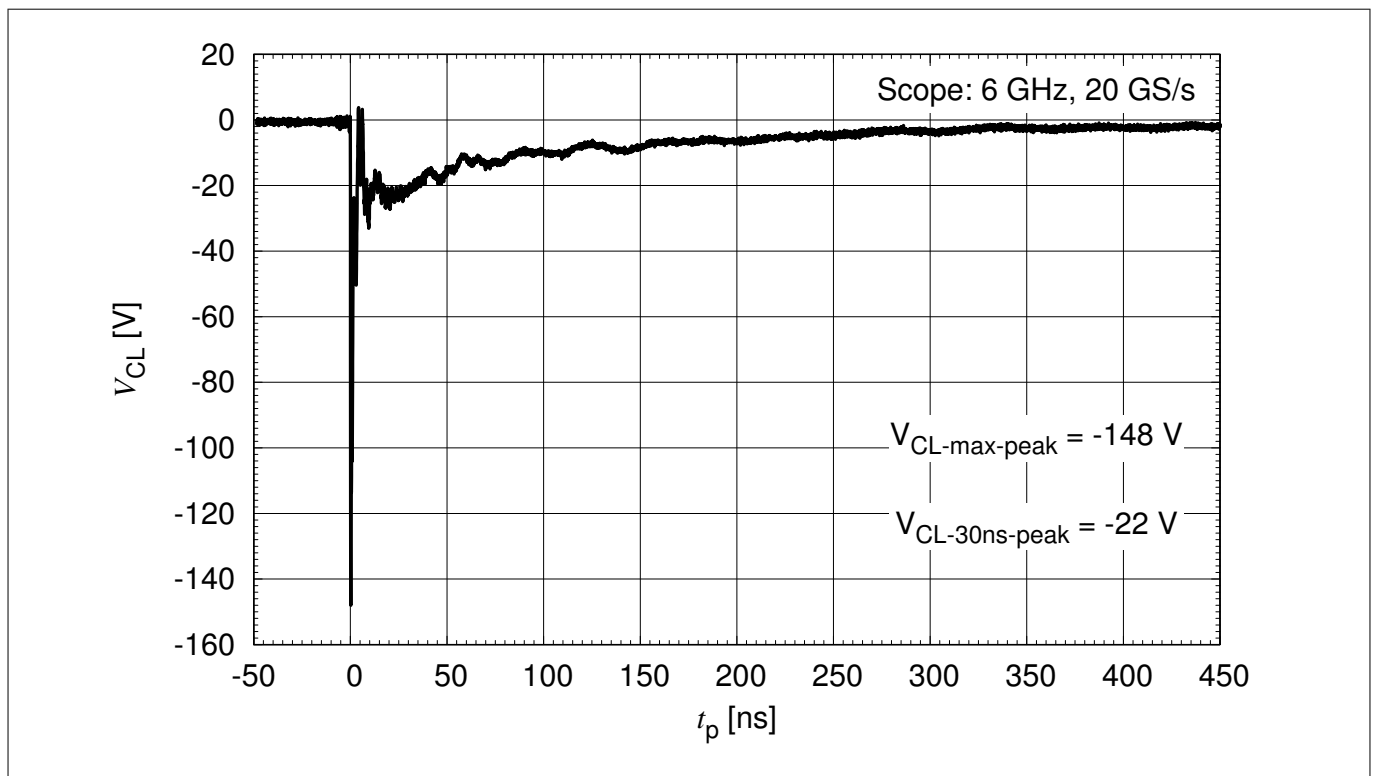


**Figure 6** Clamping voltage (ESD):  $V_{CL} = f(t)$ , 8 kV negative pulse according to IEC61000-4-2

Typical characteristic diagrams



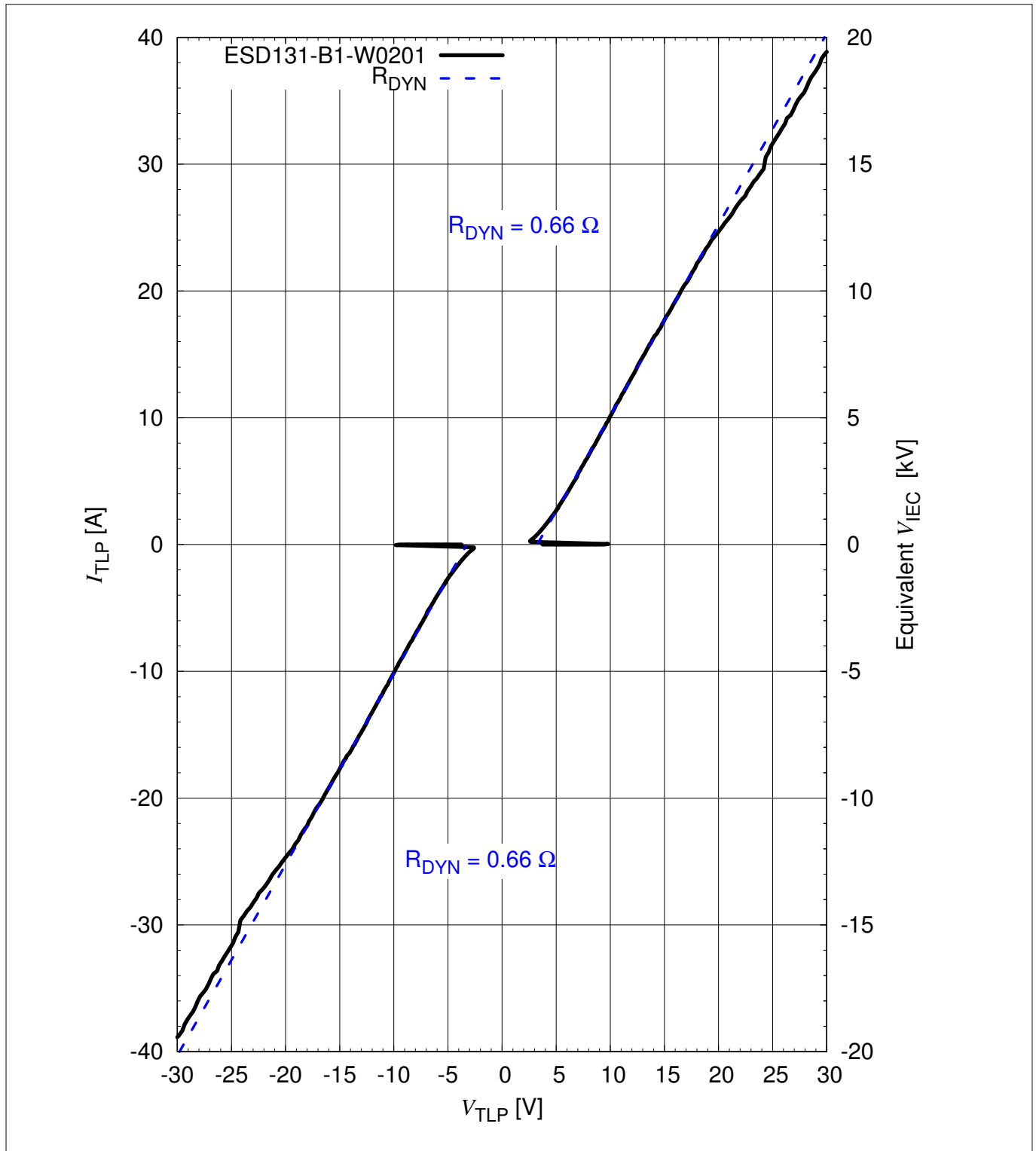
**Figure 7** Clamping voltage (ESD):  $V_{CL} = f(t)$ , 15 kV positive pulse according to IEC61000-4-2



**Figure 8** Clamping voltage (ESD):  $V_{CL} = f(t)$ , 15 kV negative pulse according to IEC61000-4-2



Typical characteristic diagrams



**Figure 9** Clamping voltage (TLP):  $I_{TLP} = f(V_{TLP})$  [1]

Typical characteristic diagrams

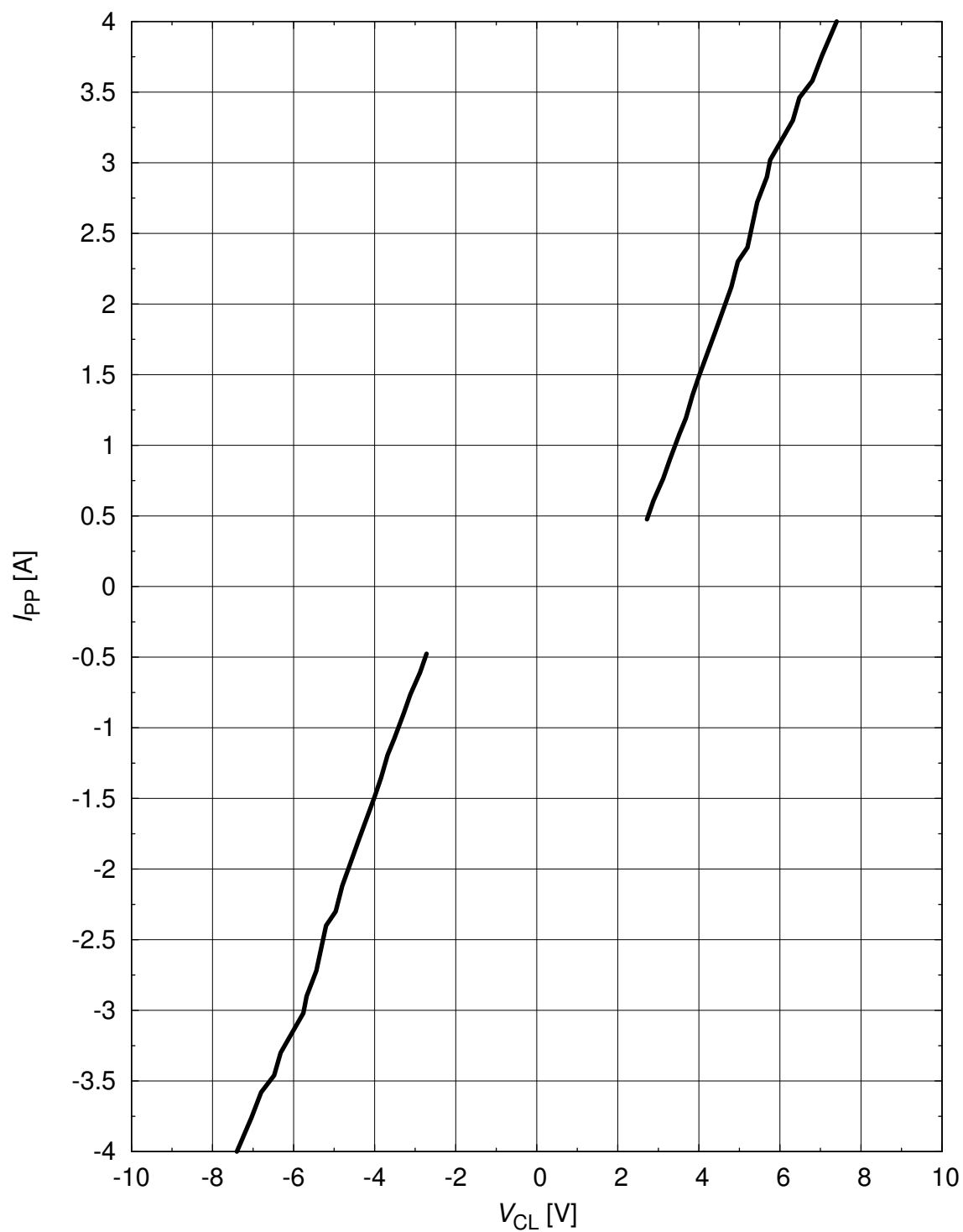
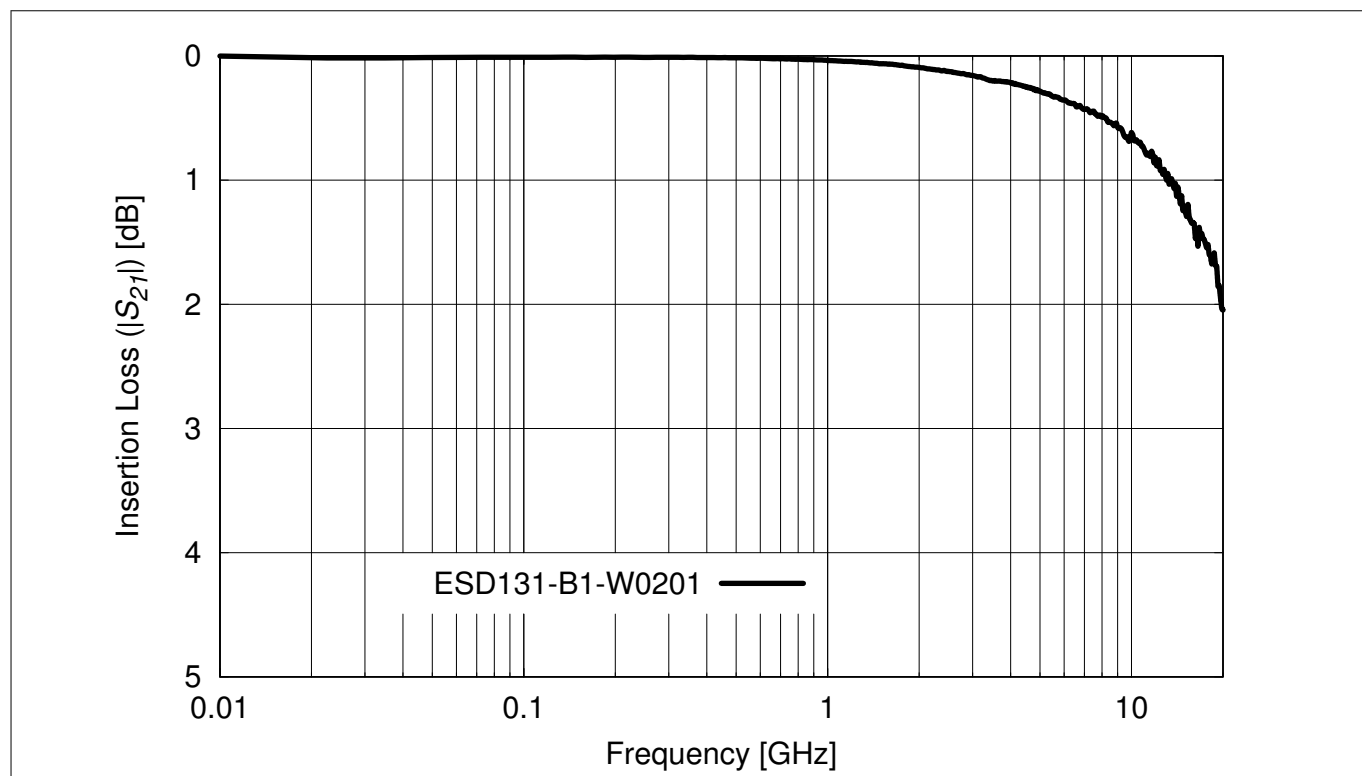


Figure 10 Clamping voltage (Surge):  $I_{PP} = f(V_{CL})$  according to IEC61000-4-5 [1]

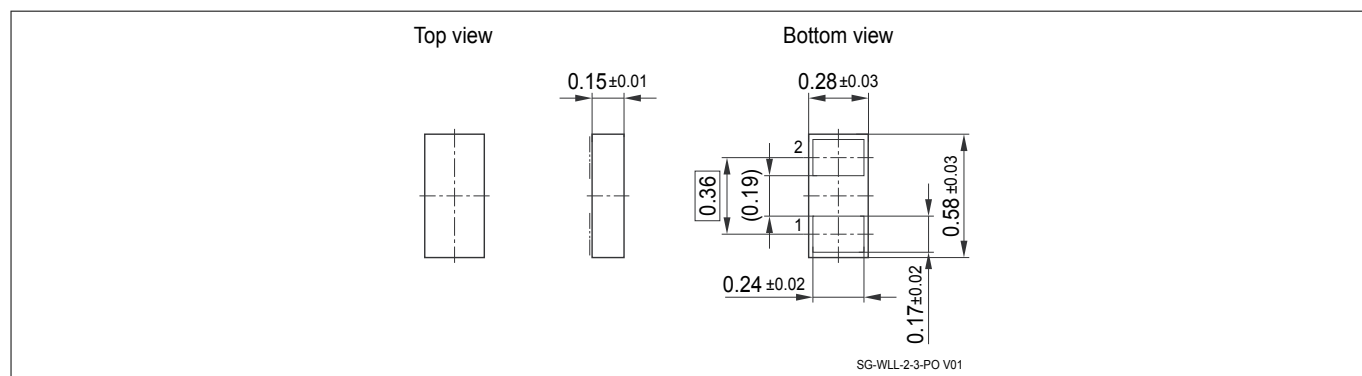
Typical characteristic diagrams



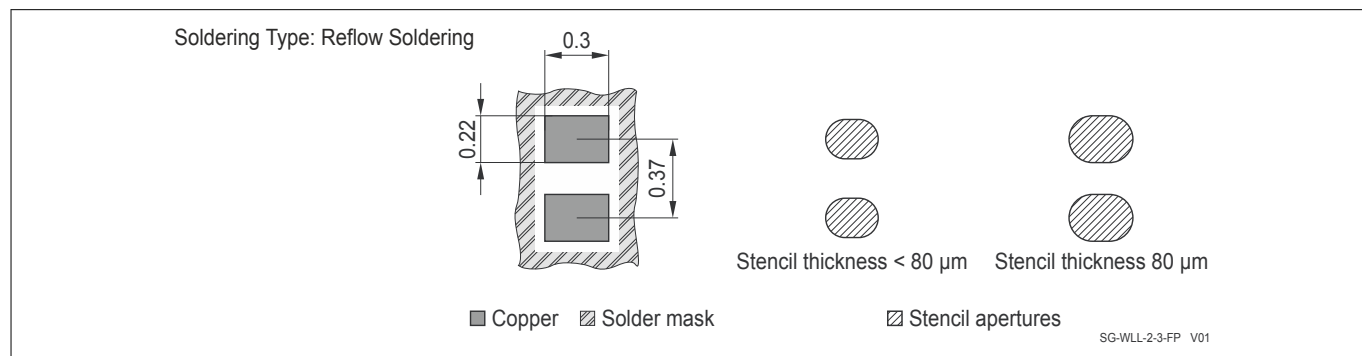
**Figure 11** Insertion loss vs. frequency in a 50  $\Omega$  system

## 4 Package information

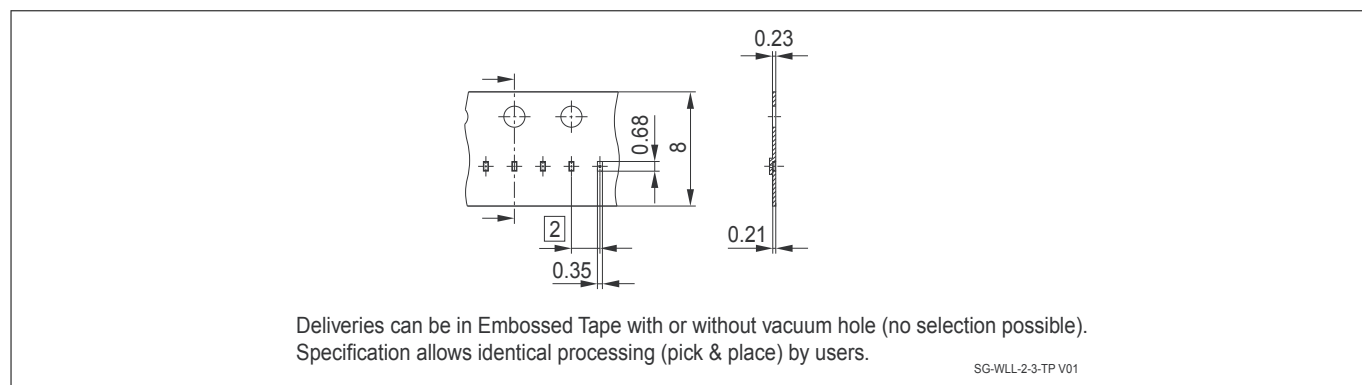
## 4.1 WLL-2-3 Package



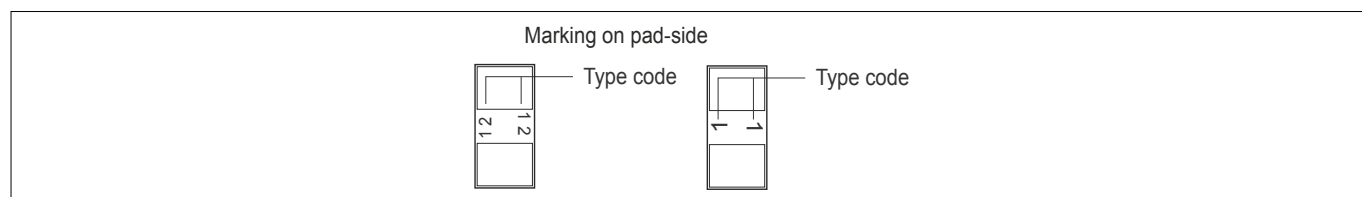
**Figure 12 WLL-2-3 package outline (dimension in mm)**



**Figure 13** WLL-2-3 footprint (dimension in mm), recommendation for Printed Circuit Board Assembly see [2]



**Figure 14 WLL-2-3 packing (dimension in mm)**



**Figure 15** WLL-2-3 marking example (see [Table 1](#))

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## References

### 5 References

- [1] Infineon AG - **Application Note AN210**: Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology
- [2] Infineon AG - Recommendation for Printed Circuit Board Assembly of Infineon WLL Packages  
[http://www.infineon.com/Packageinformation\\_WLL](http://www.infineon.com/Packageinformation_WLL)
- [3] Infineon AG - **Application Note AN392**: TVS Diodes in ChipScalePackage reduce size and save cost

## Revision history

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### Revision history: Rev.0.9, 2016-04-21

| Page or Item             | Subjects (major changes since previous revision) |
|--------------------------|--------------------------------------------------|
| Revision 1.0, 2017-03-22 |                                                  |
| Tables 2, 3, 4           | Values updated                                   |
|                          | Missing figures added                            |

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